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Front Matter: Volume 8981

, "Front Matter: Volume 8981," Proc. SPIE 8981, Physics, Simulation, and Photonic Engineering of Photovoltaic Devices III, 898101 (2 April 2014); doi: 10.1117/12.2063478

SPIE.

Event: SPIE OPTO, 2014, San Francisco, California, United States

PROCEEDINGS OF SPIE

Physics, Simulation, and Photonic Engineering of Photovoltaic Devices III

**Alexandre Freundlich
Jean-François Guillemoles**
Editors

**3–6 February 2014
San Francisco, California, United States**

Sponsored and Published by
SPIE

Volume 8981

Proceedings of SPIE 0277-786X, V. 8981

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

Physics, Simulation, and Photonic Engineering of Photovoltaic Devices III, edited by Alexandre Freundlich,
Jean-François Guillemoles, Proc. of SPIE Vol. 8981, 898101 · © 2014 SPIE
CCC code: 0277-786X/14/\$18 · doi: 10.1117/12.2063478

Proc. of SPIE Vol. 8981 898101-1

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Author(s), "Title of Paper," in *Physics, Simulation, and Photonic Engineering of Photovoltaic Devices III*, edited by Alexandre Freundlich, Jean-François Guillemoles, Proceedings of SPIE Vol. 8981 (SPIE, Bellingham, WA, 2014) Article CID Number.

ISSN: 0277-786X

ISBN: 9780819498946

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445

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